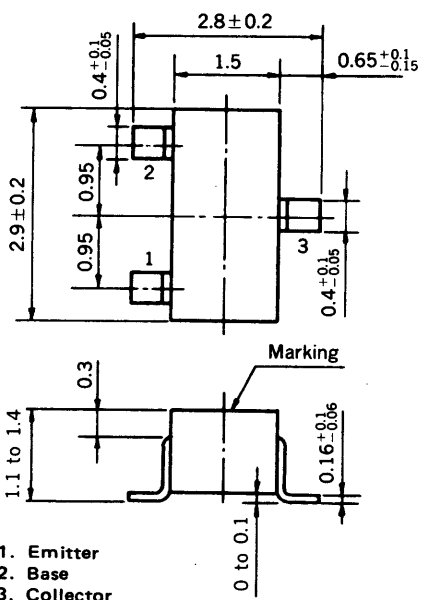


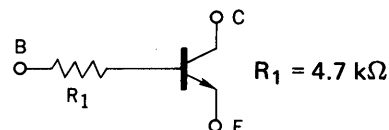
**MEDIUM SPEED SWITCHING  
RESISTOR BUILT-IN TYPE NPN TRANSISTOR  
MINI MOLD**

**PACKAGE DIMENSIONS**  
in millimeters



**FEATURES**

- Resistor Built-in TYPE



- Complementary to FN1L3Z

**ABSOLUTE MAXIMUM RATINGS**

Maximum Voltages and Currents ( $T_a = 25^\circ\text{C}$ )

Collector to Base Voltage	$V_{CB0}$	60	V
Collector to Emitter Voltage	$V_{CEO}$	50	V
Emitter to Base Voltage	$V_{EBO}$	5	V
Collector Current (DC)	$I_C$	100	mA
Collector Current (Pulse)	$I_C$	200	mA

Maximum Power Dissipation

Total Power Dissipation at $25^\circ\text{C}$ Ambient Temperature	$P_T$	200	mW
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Maximum Temperatures

Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )**

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	$I_{CBO}$			100	nA	$V_{CB} = 50\text{ V}, I_E = 0$
DC Current Gain	$h_{FE1}^*$	135	450	600		$V_{CE} = 5.0\text{ V}, I_C = 5.0\text{ mA}$
DC Current Gain	$h_{FE2}^*$	100	380			$V_{CE} = 5.0\text{ V}, I_C = 50\text{ mA}$
Collector Saturation Voltage	$V_{CE(sat)}^*$		0.04	0.2	V	$I_C = 5.0\text{ mA}, I_B = 0.25\text{ mA}$
Low-Level Input Voltage	$V_{IL}^*$		0.54	0.5	V	$V_{CE} = 5.0\text{ V}, I_C = 100\ \mu\text{A}$
High-Level Input Voltage	$V_{IH}^*$	1.2	0.71		V	$V_{CE} = 0.2\text{ V}, I_C = 5.0\text{ mA}$
Input Resistor	$R_1$	3.29	4.7	6.11	k $\Omega$	
Turn-on Time	$t_{on}$		0.03	0.2	$\mu\text{s}$	$V_{CC} = 5\text{ V}, V_{in} = 5\text{ V}$ $R_L = 1\text{ k}\Omega$ $PW = 2\ \mu\text{s}, \text{Duty Cycle} \leq 2\%$
Storage Time	$t_{stg}$		3.2	5.0	$\mu\text{s}$	
Turn-off Time	$t_{off}$		3.4	6.0	$\mu\text{s}$	

\* Pulsed:  $PW \leq 350\ \mu\text{s}, \text{Duty Cycle} \leq 2\%$

**$h_{FE}$  Classification**

Marking	L36	L37	L38
$h_{FE1}$	135 to 270	200 to 400	300 to 600

TYPICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

